

Substitute for Form 1449 A & B/PTO		Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>		Application Number	National Stage of PCT/JP03/16816 10/540995
		Confirmation Number	Unknown
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		First Named Inventor	Takashi UDAGAWA
		Art Unit	Unknown
		Examiner Name	
Sheet 1 of 1	Attorney Docket Number	Q73765	

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code ³ (if known)		
JS		US 2003/0001162	A1	01/02/2003	TAKASHI UDAGAWA
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Examiner Initials*	Cite No. ¹	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Country Code ²	Number ⁴	Kind Code ³ (if known)		
JS		EP	0 395 392	A	10/31/1990	TOKYO SHIBAURA ELECTRIC CO.
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		JP	10-242567	A	09/11/1998	TOSHIBA CORP

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation ⁴
JS		PATENT ABSTRACTS OF JAPAN Vol. 1998, No. 01, January 30, 1998 & JP 09-232685 A (TOSHIBA CORP), September 5, 1997	
		Journal of the Japanese Association for Crystal Growth, Vol. 24, No. 2, P150, (1974)	Abstract
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		Y. KUMASIRO, ET AL, "PREPARATION AND ELECTRICAL PROPERTIES OF BORON AND BORON PHOSPHIDE FILMS OBTAINED BY GAS SOURCE MOLECULAR BEAM DEPOSITION", JOURNAL OF SOLID STATE CHEMISTRY, Vol. 133, 1997, pages 269-272	
		T. IZUMIYA, ET AL, "GROWTH OF BP AND GaN/BP HETEROSTRUCTURES", INST. PHYS. CONF. SER., No. 129 CHAPTER 3, (IOP PUBLISHING LTD., UK), pages 157-162 (1992)	

Examiner Signature	<i>Harvey Schulz</i>	Date Considered	11/22/07
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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